A tomic Force Microscope: Modeling, Simulations, and Experiments

0 sam ah M. El Rifai, and K am al Youcef-Toum i

Abstract | The quality of atomic force microscope (AFM) data strongly depends on scan and controller parameters D ata artifacts can result from poor dynamic response of the instrument. In order to achieve reliable data, dynamic interactions between AFM components need to be well understood and controlled. In this paper we present a summary of our work in this direction. It includes models for the probe-sam ple interaction, scanner lateral and longitudinal dynamics, scanner creep, and cantilever dynamics The models were used to study the elect of scan parameters on the system dynamics Simulation results for both frequency response and im aging were presented. Experimental results were given supporting the simulations and dem onstrating the competence of the models. The results within will be used to develop algorithms that allow automated choice of key system parameters, guaranteeing reliable and artifact-free data for any given operating condition (sam ple, cantilever, environment). Consequently, expanding the AFM capabilities and permitting its use in a wider range of applications

K eywords | A F M, model, experiments, simulation, control

I. Introduction

The invention of scanning probe microscopy (SPM), and AFM in particular, has greatly contributed to advancing research in nano-science and technology to its current state of the art. The success of AFM as a tool in nano-sciences lies in its ability to provide controlled nano-level force or displacement. Examples include nano-scale studies of plastic deformation, microstructures and friction [1]. O ther applications require surface topography information of a sample, e.g. micro-fabrication, and nano-defects

Poor dynamic interactions between AFM components can result in corrupting AFM chta, [2], and producing data artifacts In order to achieve the best possible perform ance one needs to understand these dynamic interactions In this scope, there has been some work in the literature on developing models that describe the dynamics of an AFM cantilever during intermittent-mode operation, [3]. These models focus on probe-sample interaction at a single location on the sample surface. D ue to the low scanning speeds of this mode, these models do not account for the e®ect of scanning speed nor scanner dynamics Therefore, these models fail to capture the overall dynamics and are not suitable for analyzing contact-mode operation, where scan speed, scanner dynamics, friction, and control system all need to be considered

This paper presents a summary of research e®ort toward addressing these challenges in AFM technology. In section II, some background on AFM is given. Section III, elaborates on the motivation for this work. Models for probe-sample interactions, scanner lateral and longitudinal dynamics, scanner creep, and cantilever dynamics are presented in section IV. Sources of noise and disturbances are also discussed. B oth experimental and simulation re-



Fig. 1. Schematic diagram of AFM main components.

sults are presented and discussed in section V . Summary and concluding remarks are given in section V I.

II. Atomic Force Microscope

An AFM, Fig. 1, has three main components, namely, a scanner, a cantilever with a sharp probe, and a cantilever de° ection sensor comprised of a laser source and a position sensitive diode (PSD). The scanner, typically a piezoelectric tube, provides three-dimensional motion between the probe and a sample. Information on sample topography or local properties is obtained based on probe-sample interactions 0 ne of the main operating modes of AFM is contact mode. In this mode, the probe presses against a sample, exerting a vertical force proportional to the cantilever de° ection. The probe is then dragged against the sample along each scan line in a raster fashion. The slope at the cantilever free-endism easured and fed back. D uring scanning, a control system is used to maintain a constant slope, by adjusting the vertical displacement of the scanner. Changes in the piezo deº ection are therefore, related to changes in the sample topography. This mode is the scope of this paper.

III. Motivation

A commercial AFM was used to scan a Silicon calibration steps The AFM was run under PI control. A Silicon Nitricle cantilever was used with a resonant frequency of 13 kH z and sti®ness of O2 N =m. Scan results demonstrate the high sensitivity of collected images to scan and controller parameters (K_p and K_i). C om paring Fig. 2 (a) (72 ¹m =s; K_p = K_i = 2) to Fig. 2 (b) (96 ¹m =s; K_p = K_i = 20), some of the e[®] ects of scanning speedand controller gains on the image can be seen. Higher gains result in oscillations as the cantilever falls along the right edge of the step, with peaks probably indicating mo-



Fig. 2 A F M images (a) 72¹ m =s; K $_{\rm p}$ = K $_{\rm i}$ = 2 (b) 96¹ m =s; K $_{\rm p}$ = K $_{\rm i}$ = 20



Fig. 3. A FM images 180^{1} m =s, (a) nominal contact force, (b) smaller contact force.

m entary loss of contact between the probe and the sam ple W hile the sharp peak on the left edge of the step, Fig. 2 (b), can be attributed to a high scan speed compared to dosed loop bandwidth. The higher gains im prove tracking as the sharp left edge of the step is resolved more accurately. Figures 3 (a) and (b) were generated with a scan speed of 180 1 m =s using the same controller gains. The contact force set-point for Fig. 3 (a) is set to the manufacturer's recommended value, while Fig. 3 (b) a smaller force was used C hoosing a small contact force set-point reduces contact deformation and friction, however, it reduces stability of the contact. A s seen from Fig. 3 (b), the image generated with a small contact force has erroneous height information, due to loss of contact between the probe and the sam ple.

It has been shown that scan and control parameters dramatically impact AFM dynamics As a result, image artifact may result because of poor dynamics. In order to eliminate these types of artifacts, we need to understand the dynamic interactions between di®erent components of the AFM. This is the objective of this work.

IV. System Model

We have reported models describing the dynamics of AFM in [4], [5]. It includes probe-sam ple interaction forces, models for the piezoelectric scanner longitudinal and lateral dynamics and coupling between them, and cantilever ° exural dynamics Sources of noise and disturbances were also discussed. In this section, the models will be brie°y presented and discussed.

A. Probe-sample Interaction

A.1 In-contact Model: Vertical Forces

This contact mechanics model [6], is suitable for AFM operation in air or other media where achesion/capillary forces are dominant. It describes the achesion/capillary contact of two elastic spheres A non-cimensional transi-



Fig. 4. Schematic of probe-sample contact.

tion parameter, was de ned as

where, $\frac{3}{6}$ is the theoretical strength of the achesion junction, **R** is the reduced radius of the spheres w is the **D** up $\frac{6}{4}$ work of achesion, and **E**^{\pm} is the combined elastic modulus of the spheres. This transition parameter can be viewed as the ratio of elastic deformation to the e[®] ective range over which surface forces act. From (1), it follows that large values for , would correspond to compliant (small E^{\pm}), large spheres (**R**), and small achesion (w) contacts where small values are for sti[®] small spheres with high achesion. The model can be used to predict contact force \overline{F}_{con} , contact deformation \pm and contact radius \overline{a} .

The model is composed of three nonlinear algebraic equation that can be expressed in non-dimensional form as

$$\overline{\underline{t}} = \overline{a}^{2}_{i} \frac{4_{i}\overline{a}}{3} \overline{p} \overline{m^{2}_{i}} 1$$

$$\overline{F}_{con} = \overline{a}^{3}_{i} \overline{a}^{2} [\overline{p} \overline{m^{2}_{i}} 1 + m^{2} \sec^{1}(m)] \qquad (2)$$

$$1 = \frac{\sqrt{a}^{2}}{2} [(m^{2}_{i} 2) \sec^{1}(m) + \overline{p} \overline{m^{2}_{i}} 1] + \frac{4\sqrt{a}}{3} [\overline{p} \overline{m^{2}_{i}} 1 \sec^{1}(m)_{i} m + 1]$$

where, $m = \frac{c}{a} \operatorname{asin} F$ ig. 4, c is the radius over which surface force are present. The use of such continuum models to describe nano-contacts has been supported by m any experiments. The level at which continuum models break-down is not all clear [7].

A .2 In-contact Model: Lateral Forces

A sthe probe is chagged against the sam ple while in contact, a frictional shear force develops A t nano-level contacts, experiments have revealed the dependence of friction force on contact area, [1]. For our purposes we are interested in simulating the e[®]ect of sliding friction force on the cantilever dynamics during scanning. A sa rst order approximation, we will assume that the instantaneous friction force is directly proportional to the instantaneous contact area ($\approx a^2$). This model does not consider any explicit dependence of friction on scanning speed. A lthough contact models were originally developed for static loading, it has been shown in [1], that it holds under sliding conditions with not very high sliding speeds. When the probe and sam ple are out of contact the friction force is set to zero.



Fig. 5 Cross section of an eccentric piezoelectric tube.

A.3 0 ut-of-contact Model: Vertical Forces

W hen the probe and sample are not in contact, van der W aals forces between two spheres are assumed to be the cominant interaction.

A.4 Point of Contact

At the limit of loss of contact, the contact radius \overline{a} ! O Substituting this into eqn. (2), gives the force and separation at that limit. This is used to impose continuity on the force between models of sections IV -A .1 and IV -A .3

B. Scanner Lateral D ynamics

There are two main designs for A FM. In one design, the cantilever is 'xed and a sample is placed on the scanner which moves it relative to the cantilever. This design, generally, limits the maximum size and weight of the sample. In the second design, Fig. 1, the cantilever is attached to the scanner that moves it relative to a stationary sample. In this paper the model presented is for the second, more popular design.

The scanner is a thin-walled piezoelectric tube that has four electroces of equal segments on its outer surface, and either a single or four electroce on its inner surface. A pplying a voltage V_z , to its inner electroce(s) results in extension motion, (in the Z-axis). Motion in the X or Y axis is typically generated by subjecting two opposite electroces to two voltage signals, $(V_{x_+}; V_{x_i})$ and $(V_{y_+}; V_{y_i})$, with the same magnitude but are out of phase.

In [8], [9], a model for an ideal uncoupled tube scanner was presented D ue to inevitable machining tolerance, eccentricity is always present in the tube. Typically, a maximum of 50 ¹m for a 127mm diameter tube, [10]. This seemingly small eccentricity is in fact significant as the cantilever-de^o ection sensor has A ngstrom rm s resolution. The model is based on two eccentric cylinders F ig. 5, with eccentricity \pm_x and \pm_y from the geometric center of the outer cylinder, 0_o. The tube is \pm_x and at one end and free at the other. A cantilever holder of mass m_{sh} is attached to its free end. The model is based on elementary bending the ory for thin-walled members. The main assumptions are small deformations and angles, linear elastic material, and

negligible e[®]ects of rotary inertia and shear deformation. B elow, eqn. (3), gives the transfer function between the input voltages and the lateral displacement u_j ; (j = 1; 2), for i^{α} number of modes E quations (4), and (5) give the output equations for displacements in the X and Y -directions x_p and y_p , respectively. The scanner's free end rotations (i.e. slopes) about X and Y -axes μ_{px} and μ_{py} , respectively, are given in eqn.'s (6) and (7).

$$u_{j} = \frac{\mathbf{X}}{\sum_{i=1}^{\circ} \frac{\mathbf{x}_{i} V_{x_{i}} + \mathbf{x}_{i} V_{x_{i}} + \mathbf{x}_{i} V_{y_{i}} + \mathbf{x}_{i} V_{y_{i}} + \mathbf{x}_{i} V_{z}}{S^{2} + 2^{3}_{iu_{j}} ! u_{j} S + ! \frac{2}{iu_{j}}}$$
(3)

$$\mathbf{x}_{\mathbf{p}} = \cos(\boldsymbol{\mu}_{\pm}) \mathbf{u}_1; \sin(\boldsymbol{\mu}_{\pm}) \mathbf{u}_2 \qquad (4)$$

$$y_p = \sin(\mu_{\pm}) u_1 + \cos(\mu_{\pm}) u_2$$
 (5)

$$\mu_{\mathrm{px}} = \sin(\mu_{\mathrm{t}}) \frac{\mathcal{Q}_{\mathrm{u}}}{\mathcal{Q}_{\mathrm{z}}} + \cos(\mu_{\mathrm{t}}) \frac{\mathcal{Q}_{\mathrm{u}}}{\mathcal{Q}_{\mathrm{z}}} \tag{6}$$

$$\mu_{y} = \cos(\mu_{\pm}) \frac{\omega_{1}}{\omega_{Z}}; \sin(\mu_{\pm}) \frac{\omega_{2}}{\omega_{Z}}$$
 (7)

C. Scanner Longitudinal Dynamics

The details of the model are given in [11]. The main as sumptions are similar to those of section IV-B. The transfer function between input voltages and displacement of the tube's free-end z_p , for j^{α} number of modes is given as

$$z_{p} = \frac{\mathbf{X}}{\sum_{j=1}^{o} \frac{\mathbf{y}_{x_{+}} + \mathbf{y}_{x_{+}} + \mathbf{y}_{jx_{i}} + \mathbf{y}_{x_{i}} + \mathbf{y}_{jy_{+}} + \mathbf{y}_{jy_{+}} + \mathbf{y}_{jy_{i}} + \mathbf{y}_{jz} + \mathbf{y}_{z}}{s^{2} + 2^{2} \mathbf{y}_{z_{p}} ! \mathbf{y}_{z_{p}} \mathbf{s} + ! \mathbf{y}_{z_{p}}^{2}}}$$
(8)

D. Scanner C reep

The response of a piezoelectric actuator to a rapid change in input voltage, Fig. 6, consists of two main parts The initial part of the response occurs over a time scale dictated by the mechanical resonance of the actuator. This is followed by a slow creeping response occuring over 10s of seconds and amounting to as much as 20% of the total response. The rate and amount of creep strongly depend on the piezoelectric material. Experimental frequency response of piezoelectric actuators displays very little variation in phase at low frequency between input voltage and displacement. 0 n the other hand, a slight decrease in gain is observed with increasing frequency. It is possible to sim ulate creep behavior using a suitable LTI model. The relative degree is number of poles minus the number of zeros of the transfer function. The transfer function between the input voltage and actuator displacement should have a relative degree zero at frequencies much lower than the actuator's resonance frequency. This model assumes that the ratio between the amount of creep and the fast scanner displacement is independent of input amplitude. The assumption will be experimentally tested.

E. Cantilever Flexural Dynamics

T his dynamic model for the cantilever motion neglects effects of shear deformation and rotary inertia, and is based



Fig. 6. Experim ental creep response.

on elementary bending theory. The cantilever slope (angle), z_c^0 , is measured relative to its base motion, $z_p(t)$. The boundary conditions are taken as zero de° ection and slope relative to the base at the ⁻xed end, and zero moment and shear force at the free-end. For simplicity, the cantilever is assumed to be aligned with the X-axis. The transfer function governing the cantilever's response is given by,

$$Z_{C}^{Q}(s) = \frac{\mathbf{X}^{z}}{m=1} \frac{a_{22m} s^{2} + a_{12m} s}{s^{2} + 2^{3} c_{m} ! c_{m} s + ! c_{m}^{2}} z_{p}(s) + \frac{a_{2m} s^{2} + a_{1\mu m} s}{s^{2} + 2^{3} c_{m} ! c_{m} s + ! c_{m}^{2}} \mu_{py}(s) + \frac{a_{fm}}{s^{2} + 2^{3} c_{m} ! c_{m} s + ! c_{m}^{2}} f(z_{c}; z_{p}; \mu_{py}; z_{s})$$
(9)

where, $f(z_c; z_p; \mu_{py}; z_s)$ is the probe-sam ple force, and z_s is the sam ple height.

F. Sensor 0 utput

The optical-lever sensor m easures the absolute angle of the cantilever's free-end. Therefore, the PSD output $y_{_{\rm PSD}}$, is given by,

$$y_{PSD} = \mu_{PV} i z_c^0 \qquad (10)$$

G. Disturbances

Thermal noise or B rownian motion contributes to a funcham ental source of noise in A F M. A t therm al equilibrium, the mean value of the cantilever potential energy has to equal $\frac{1}{2}k_BT$, where $k_B = 1:38$ £ 10²³ J=K is B oltzmann's constant, and T is the absolute temperature in K elvin. The cantilever's free end will oscillate with a RMS value, $z_c^{O^{ms}} = \frac{3}{\mathcal{A}_c} z_c^{rms} = \frac{3}{\mathcal{A}_c} \sqrt[4]{\frac{k_BT}{k_c}}$, where k_c is the cantilever sti®ness, and L_c is the cantilever length. This expression is valid for a free standing cantilever. If the cantilever is in contact with a sample, the expression has to be modi- $\bar{}$ ed by including the sam ple e[®]ective sti[®]ness in k_c. A nother source of disturbance is laser back-action. It is due to incidence of photon ° ux from the optical sensor on the cantilever. Both thermal and back-action noises will be e[®]ectively modeled as zero-mean white noise force disturbances with a combined constant intensity $\mu \pm (t; i)$.



Fig. 7. Simulation: Quasi-static normalized force-separation curve.



Fig. 8 Experim ental force-displacem ent curve.

Feedback measurement noise arising from the optical sensor can be due to shot noise, a fundamental noise for these sensors, in addition to noise from sensor electronics Shot noise can also be modeled as white noise.

V. Results

A. Quasi-static Force-separation Curve

The models of sections IV -A.1, IV -A.3 were used to generate the composite force-separation curve of Fig. 7. Parameters used to generate the curve are given in [4]. It is worth noting that eqn. (2) can predict an instability that has been observed in quasi-static experiments This instability occurs when an approaching/receding probe jumps in/out (pull-in/pull-out points), of contact with the sam ple surface corresponding to a sudden jump in the contact area. The actual point of instability on the force-separation curve will depend on the $sti^{(n)}$ ness of the cantilever k_{c_0} as shown in Fig. 7. An experimental force-separation curve is shown in Fig. 8 where ^a denotes use of estimated calibration factors It shows the same characteristic produced by the model in Fig. 7, except that hysteresis is observed in the penetration region as the approach and retract lines are not the same.



Fig. 9 Schematic of probe-sample contact.

B. In-contact D ynamics Simulations

The probe-sample interaction force $f(z_c; z_p; \mu_{py}; z_s)$ is a nonlinear function of probe-sample separation, and depends on geometry, environment, and probe and sample material properties. To obtain a linear model to be used for analysis, the force was expanded in a Taylor series and linear terms were retained, giving,

$$f(z_{c}; z_{p}; \mu_{py}; z_{s}) = g_{c}z_{c} + g_{z}z_{p} + g_{\mu_{py}}\mu_{py} + k_{s}z_{s} + H : 0 :T$$
(11)

 $k_{\rm s}$ can be considered as a linear e[®]ective probe-sample contact sti[®]ness The probe-sample contact can be represented schematically as in Fig. 9, where again $z_{\rm o}$ is measured relative to $z_{\rm p}$. The contact and cantilever sti[®]ness $k_{\rm c}$ are represented as two springs in series The contact sti[®]ness does not change the order of the model, but has a great impact on the system's zeros Substituting equation into eqn. (10 gives the overall model. The transfer function of interest is between V_z and $y_{\rm PSD}$. This describes the A F M Z-dynamics which we will focus on in this work.

The model used in this study included four bending modes and two extension modes for the scanner, and one bending mode for the cantilever. The parameter values used are given in [11]. The ratio of sample to cantilever sti®ness $\frac{k_s}{k_c}$, proved to be an important parameter. Changes in this ratio have two main e[®]ects on the model, namely, change in the transfer function DC gain and changes in the frequency of the zeros associated with the scanner bending modes 380H z and 2kH z. Figure 10 shows the simulated frequency response of the model for di®erent ratios of sti®nesses For large ratios (e.g. $\frac{k_s}{k_c} = 7$), the zeros have a higher frequency than the mode. For smaller ratios (e.g. $1 \cdot \frac{k_s}{k_c} \cdot 2$, the frequency decreases to be below that of the mode. This change in pole-zero pattern is referred to as pole-zero ° ipping. Moreover, for some value ($\frac{k_{e}}{k_{c}}$ ¼ 4), there is pole-zero cancelation and the bending modes are unobservable. Figure 11, presents a pole-zero map of the rst two modes for dimension values of $\frac{k_{s}}{L}$. As a result, as the zeros move away from the mode, the resonance peak appears more prominent in the response. Further, when $\frac{K_s}{K_c}$ is either too large or too small, the DC gain reaches a



Fig. 10 Simulation: In-contact frequency response for di®erent ratios of sample to cantilever sti®ness $\frac{k_{e}}{k_{e}}$.



Fig. 11. Pole-zero map as a function of $\frac{k_{sc}}{k_c}$: (left) zoom on 2kH z mode, (right) zoom on 380H z mode.

limit controlled by k_c and k_s , respectively. For intermediate values the DC gain will depend on both sti®nesses and changes in k_s due to di®erent set-pints or input amplitudes will change the DC gain, and zeros location.

C. In-contact D ynamics Experiments

To investigate in-contact AFM dynamics and validate the models two samples were chosen for experiments namely, a G lassanda Polycim ethylsiloxane (PDMS), sample having Young's moduli of elasticity of 6O and 25M Pa, respectively. Two di®erent cantilevers were used C antilever A has an estimated sti®ness of OOBN =m and resonance frequency of 13kH z. C antilever B has an estimated sti®ness of O14N =m and resonance frequency of 14kH z. D i®erent set-points and input am plitudes were used to study the e®ect of these parameters on the dynamics

Figure 12, shows the force-displacement curve for the G lass sample. The points labeled on the plot are the force set-points used in the frequency response experiments N ote that the local sensitivity around the set-points (cantilever de° ection per scanner input voltage) is smaller for the larger force set-point. This suggests reduced contact sti®ness potentially due to plastic deformation in the contact. The e®ects of force set-point on the dynamics are seen in Fig. 13. For the larger set-point, 17nN, the DC



Fig. 12 Force-displacement curve using cantilever A with a G lass sample.



Fig. 13. In-contact frequency response using cantilever A with a G lass sample: same amplitude for di®erent set-points

gain is smaller and the 38OH z bencing mode has a smaller resonance peak. The decrease in D C gain suggest that the e[®]ective contact sti[®]ness has decreased, hence, the scanner displacement (Fig. 9) is transmitted more to the smaller sti[®]ness; the contact's The smaller resonance peak could be due to two reasons; the frequency of the zero-pair associated with the bencing mode has slightly decreased for the larger set-point. If ence, allowing the contribution of the bencing mode to appear less prominent in the response. In addition, it could be a result of changes in the dissipative properties of the contact with changes in the set-point. It is portant to realize that the bencing mode resonance frequency did not change. The contact forces are orders of magnitude smaller than the force the scanner can provide, (* 1OSnN vs * 1N).

The e[®]ect of excitation am plitude, i.e. sam ple topography, on the frequency response is shown in Fig. 14, for set-point of 14nN. It is seen that the larger the am plitude of excitation, the smaller the DC gain. For the larger input am plitude, more plastic deformation might occur in the contact due to the larger contact force, which in turn reduces the e[®]ective contact sti®ness A s before, more displacement is transmitted to the sam ple, hence, reducing the DC gain. The more plastic deformation there is, the smaller the dange in contact sti®ness and hence DC gain. The resonance peak also danges due to danges in the



Fig. 14 In-contact frequency response using cantilever A with a Glass sample: 14nN for di®erent amplitudes



Fig. 15 Force-displacement curve using cantilever B with a PDMS sample.

frequency of the bending mode zero-pair.

Figure 15, shows the force-displacement curve for the PD MS sample. The penetration region seem squite nonlinear. This im plies that what is being measured by the PSD signal, at least in part, is the deformation of the sample. The observations in Fig. 16, are that increasing the input am plitude reduces the D C gain, the frequency of bendingmode zeros, and consequently increasing resonance peak. This suggests that the contact sti®nessincreases with larger am plitude, which agrees with Fig. 15. In addition, increasing set-point, Fig. 17, results in pole-zero ° ipping for the rst two bending modes. The frequency of the zeros changes from being higher to being lower than that of the associated mode. This is in agreement with model predications in section V-B, (Fig. 10). Hence, contact and cantilever sti®ness values are relatively close.

The model can be further improved on to include nonlinearities in the contact a®ecting the D C gain and damping. These nonlinearities depend in great part on properties of the sample. Hence, the form of this dependence is not known. It is possible to account for it in the model by generalizing the probe-sample force to include dissipative terms and retain higher order terms Therefore, eqn. (11), changes to f (z_c ; z_c ; z_p ; z_p ; μ_p y; μ_p y; p_s).



Fig. 16. In-contact frequency response using cantilever B with a PDMS sample 36 nN for di®erent amplitudes



Fig. 17. In-contact frequency response using cantilever B with a PDMS sample: 17nm amplitude for di®erent set-points

D. Scanning Simulation vs Experiments

The models were used to perform scanning simulations The sample shape used in simulation is an experimental AFM image of calibration steps Figure 18 shows the simulated image vs the actual sample. It can be seen that the sampled and averaged image generated from the piezo voltage, V_z , coes not correspond well to the actual image. The cantilever oscillations causes it to loose contact with the sample and the hammering action could in fact be chanaging to the actual sample. AFM image shown in Fig. 19 is of the steps used in the simulation. The simulations predict the actual response well. A lso note the oscillations observed in Fig. 19. These oscillations introduces an artifact that could be interpreted incorrectly as surface roughness

E. Performance Limitations Due to Scanner Bending Mode

The coupling between scanner bending and extension modes has a great impact on AFM performance in several ways W hen the scanner is commanded to move up/down, there is a slight bending motion that gets detected by the PSD. The scanner is typically calibrated by imaging a stanchard of known height usually in the 100nm range. D uring imaging, the PSD signal will change due to the sample topography as well as to bending of the actuator. Imagining a sample of a di®erent height will result in a slightly



Fig. 18 Scanning simulation results of calibration steps using a PI controller.



Fig. 19. AFM image of calibration steps using a PI controller.

d[®]erent calibration factor, even if the nonlinearity of the scanner was not a concern. The change in calibration due to scanner bending is typically less than 1%.

Scanner extension mode is typically around 4 to 8kH z. The required feedback bandwidth during scanning can be estimated based on scan rate and image resolution (num ber of data points per scan line). For a scan rate of 2H z and a resolution of 512, the bandwidth would be $2 \pm 2 \pm 512 = 1000 = 2048 \text{ kH z}$ Hence, the bending resonance at 380H z would be well within the feedback bandwidth. Tuning the controller gains to achieve a high bandwidth would result in oscillations in the image. This can be seen in Fig. 20 where oscillations due to the 380H z mode is observed in an experimental AFM image. Increasing force set-point tends to make the bending mode less observable by moving the zeros closer to that poles However, the high contact force may cause clamage to the sample and/or reduce image resolution. A lternatively, the bandwidth can be reduced along with scan speed. This results in a longer scan time making scanner creep more observable in the im age. Further, since the bending mode is the closest mode to the j! axis, Fig. 11, it has a great e[®]ect on the robustness of the feedback system. Pole-zero ° ipping can cause closed loop poles to cross the j! axis causing feedback instability.

F. CreepCompensation

A 3rd order LTI ⁻lter was used to compensate for creep in the AFM piezoelectric scanner, [12]. The performance



Fig. 20 0 scillations due to scanner bending mode in experimental AFM image of a 1046 nm Silicon step.



Fig. 21. A FM im age of 530nm Silicon steps, with and without creep compensation, 28¹m =s.

of the ⁻lter was tested, e.g. Fig. 21, by imaging 53O and 159Onm steps W ith compensation, the creep response was reduced to 26% with compensation for images taken over 6:67 minutes C ompensation did not degrade for larger steps suggesting that the a linear model for creep may be justi⁻ed. N onlinearities in the scanner fast displacement can be dealt with separately. C losed loop operation can o[®]er better creep compensation but is a more expensive option. In addition, it reduces image resolution for small scans/sam ple features due to limited dynamic range of the sensors at a high bandwidth.

VI. Summary and Conclusion

The quality of AFM clata strongly depends on scan and controller parameters D ata artifacts can result from poor dynamic response of the instrument. In order to achieve reliable data, dynamic interactions between AFM components need to be well understood and controlled. In this paper we presented a summary of our work in this direction. It included models for the probe-sample interaction, scanner lateral and longitudinal dynamics scanner creep and cantilever dynamics. The models were used to study the e[®]ect of scan parameters on the system dynamics. Simulation results for both frequency response and im aging were presented. Experimental results were given supporting the simulations and demonstrating the competence of the models The results within will be used to develop algorithms that allow automated choice of key system parameters, guaranteeing reliable and artifact-free data for any given operating condition (sample, cantilever, environment). Consequently, expanding the AFM capabilities and permitting its use in a wider range of applications

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